

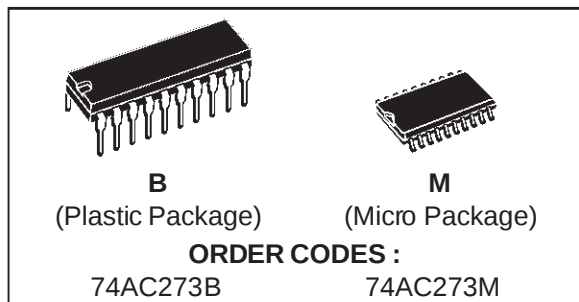
OCTAL D-TYPE FLIP FLOP WITH CLEAR

- HIGH SPEED:
 $f_{MAX} = 190 \text{ MHz (TYP.)}$ at $V_{CC} = 5V$
- LOW POWER DISSIPATION:
 $I_{CC} = 8 \mu A \text{ (MAX.)}$ at $T_A = 25^\circ C$
- HIGH NOISE IMMUNITY:
 $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (MIN.)}$
- 50Ω TRANSMISSION LINE DRIVING CAPABILITY
- SYMMETRICAL OUTPUT IMPEDANCE:
 $|I_{OH}| = I_{OL} = 24 \text{ mA (MIN)}$
- BALANCED PROPAGATION DELAYS:
 $t_{PLH} \equiv t_{PHL}$
- OPERATING VOLTAGE RANGE:
 $V_{CC} \text{ (OPR)} = 2V \text{ to } 6V$
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 273
- IMPROVED LATCH-UP IMMUNITY

DESCRIPTION

The AC273 is a high-speed CMOS OCTAL D-TYPE FLIP FLOP WITH CLEAR fabricated with sub-micron silicon gate and double-layer metal wiring C²MOS technology. It is ideal for low power applications maintaining high speed

PRELIMINARY DATA



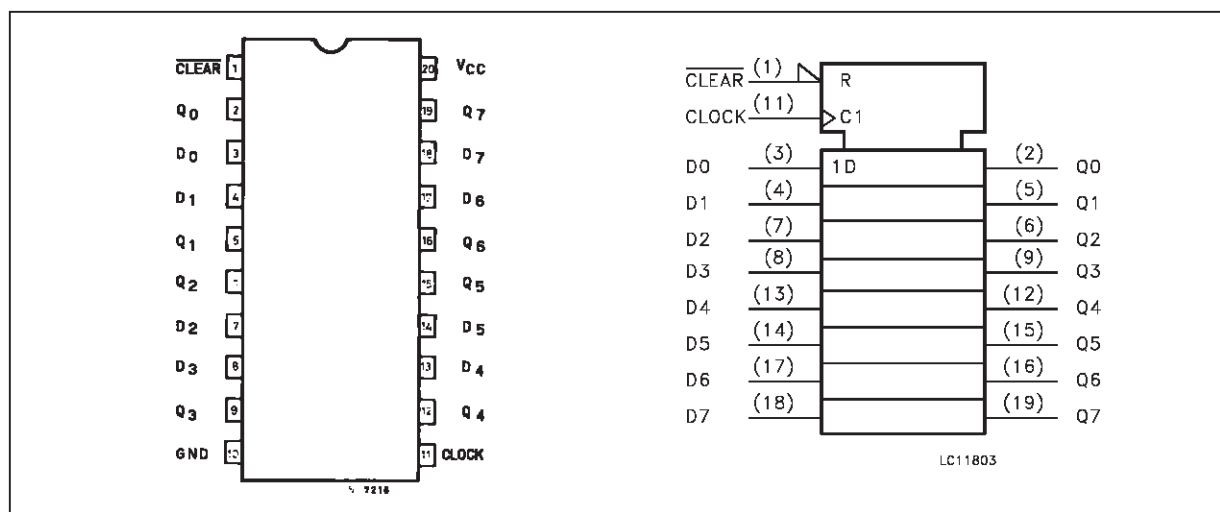
operation similar to equivalent Bipolar Schottky TTL.

Information signals applied to D inputs are transferred to the Q output on the positive going edge of the clock pulse.

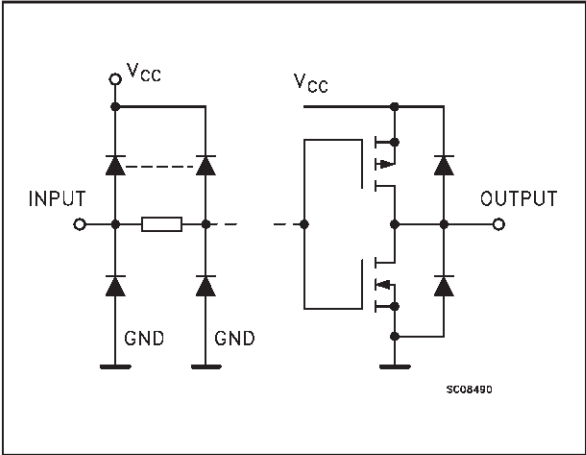
When the CLEAR input is held low, the Q outputs are held low independently of the other inputs .

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

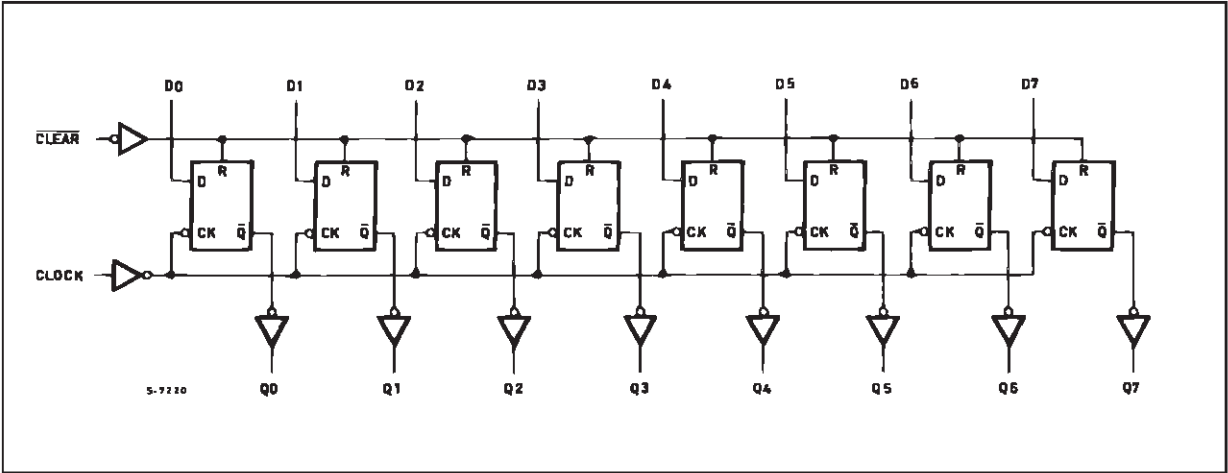
PIN No	SYMBOL	NAME AND FUNCTION
1	$\overline{\text{CLEAR}}$	Asynchronous Master Reset (Active LOW)
2, 5, 6, 9, 12, 15, 16, 19	Q0 to Q7	Flip-Flop Outputs
3, 4, 7, 8, 13, 14, 17, 18	D0 to D7	Data Inputs
11	CLOCK	Clock Input (LOW-to-HIGH, Edge-Triggered)
10	GND	Ground (0V)
20	V _{CC}	Positive Supply Voltage

TRUTH TABLE

INPUTS			OUTPUTS	FUNCTION
$\overline{\text{CLEAR}}$	D	CLOCK	Q	
L	X	X	L	CLEAR
H	L		L	
H	H		H	
H	X		Q _n	NO CHANGE

X: Don't Care

LOGIC DIAGRAMS



This logic diagram has not be used to esimate propagation delays

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Current	± 50	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 400	mA
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	2 to 6	V
V_I	Input Voltage	0 to V_{CC}	V
V_O	Output Voltage	0 to V_{CC}	V
T_{op}	Operating Temperature:	-40 to +85	°C
dt/dv	Input Rise and Fall Time $V_{CC} = 3.0, 4.5$ or 5.5 V(note 1)	8	ns/V

1) V_{IN} from 30% to 70% of V_{CC}

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions		Value					Unit	
		V _{CC} (V)		T _A = 25 °C			-40 to 85 °C			
				Min.	Typ.	Max.	Min.	Max.		
V _{IH}	High Level Input Voltage	3.0	V _O = 0.1 V or V _{CC} - 0.1 V	2.1	1.5		2.1		V	
		4.5		3.15	2.25		3.15			
		5.5		3.85	2.75		3.85			
V _{IL}	Low Level Input Voltage	3.0	V _O = 0.1 V or V _{CC} - 0.1 V		1.5	0.9		0.9	V	
		4.5			2.25	1.35		1.35		
		5.5			2.75	1.65		1.65		
V _{OH}	High Level Output Voltage	3.0	V _I (*) = V _{IH} or V _{IL}	I _O =-50 μA	2.9	2.99		2.9		V
		4.5		I _O =-50 μA	4.4	4.49		4.4		
		5.5		I _O =-50 μA	5.4	5.49		5.4		
		3.0		I _O =-12 mA	2.56			2.46		
		4.5		I _O =-24 mA	3.86			3.76		
		5.5		I _O =-24 mA	4.86			4.76		
V _{OL}	Low Level Output Voltage	3.0	V _I (*) = V _{IH} or V _{IL}	I _O =50 μA		0.002	0.1		0.1	V
		4.5		I _O =50 μA		0.001	0.1		0.1	
		5.5		I _O =50 μA		0.001	0.1		0.1	
		3.0		I _O =12 mA			0.36		0.44	
		4.5		I _O =24 mA			0.36		0.44	
		5.5		I _O =24 mA			0.36		0.44	
I _I	Input Leakage Current	5.5	V _I = V _{CC} or GND			±0.1		±1	μA	
I _{CC}	Quiescent Supply Current	5.5	V _I = V _{CC} or GND			8		80	μA	
I _{OLD}	Dynamic Output Current (note 1, 2)	5.5	V _{OLD} = 1.65 V max					75	mA	
V _{OHD} = 3.85 V min							-75	mA		

1) Maximum test duration 2ms, one output loaded at time

2) Incident wave switching is guaranteed on transmission lines with impedances as low as 50 Ω.

(*) All outputs loaded.

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, $R_L = 500 \Omega$, Input $t_r = t_f = 3 \text{ ns}$)

Symbol	Parameter	Test Condition		Value					Unit
		V _{CC} (V)		T _A = 25 °C			-40 to 85 °C		
				Min.	Typ.	Max.	Min.	Max.	
t _{PLH}	Propagation Delay Time CLOCK to Q	3.3 ^(*)		4.0	8.0	12.5	3.0	14.0	ns
t _{PHL}		5.0 ^(*)		3.0	5.5	9.0	2.5	10.0	
t _{PHL}	Propagation Delay Time CLEAR to Q	3.3 ^(*)		4.0	8.5	13.0	3.0	14.0	ns
		5.0 ^(**)		3.0	6.5	10.0	2.5	11.0	
t _w	CLEAR pulse Width	3.3 ^(*)		5.5			6.0		ns
		5.0 ^(**)		4.0			4.5		
t _w	CLOCK pulse Width	3.3 ^(*)		5.5			6.0		ns
		5.0 ^(**)		4.0			4.5		
t _s	Setup Time D to CK HIGH or LOW	3.3 ^(*)		5.5			6.0		ns
		5.0 ^(**)		4.0			4.5		
t _h	Hold Time D to CK HIGH or LOW	3.3 ^(*)		1.5			1.5		ns
		5.0 ^(**)		1.5			1.5		
t _{REM}	Recovery Time CLEAR to CLOCK	3.3 ^(*)		4.0			4.5		ns
		5.0 ^(**)		3.0			3.0		
f _{MAX}	Maximum Clock Frequency	3.3 ^(*)		90			75		MHz
		5.0 ^(**)		140	190		125		

*) Voltage range is 3.3V ± 0.3V

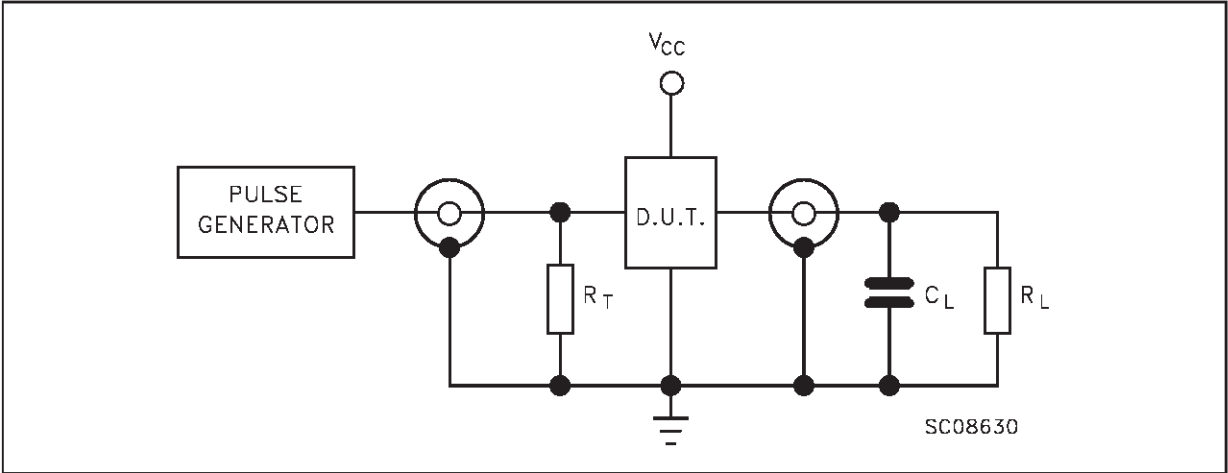
(**) Voltage range is 5V ± 0.5V

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions		Value					Unit
		V _{CC} (V)		T _A = 25 °C			-40 to 85 °C		
				Min.	Typ.	Max.	Min.	Max.	
C _{IN}	Input Capacitance	5.0			4				pF
C _{PD}	Power Dissipation Capacitance (note 1)	5.0	f _{IN} = 10 MHz		TBD				pF

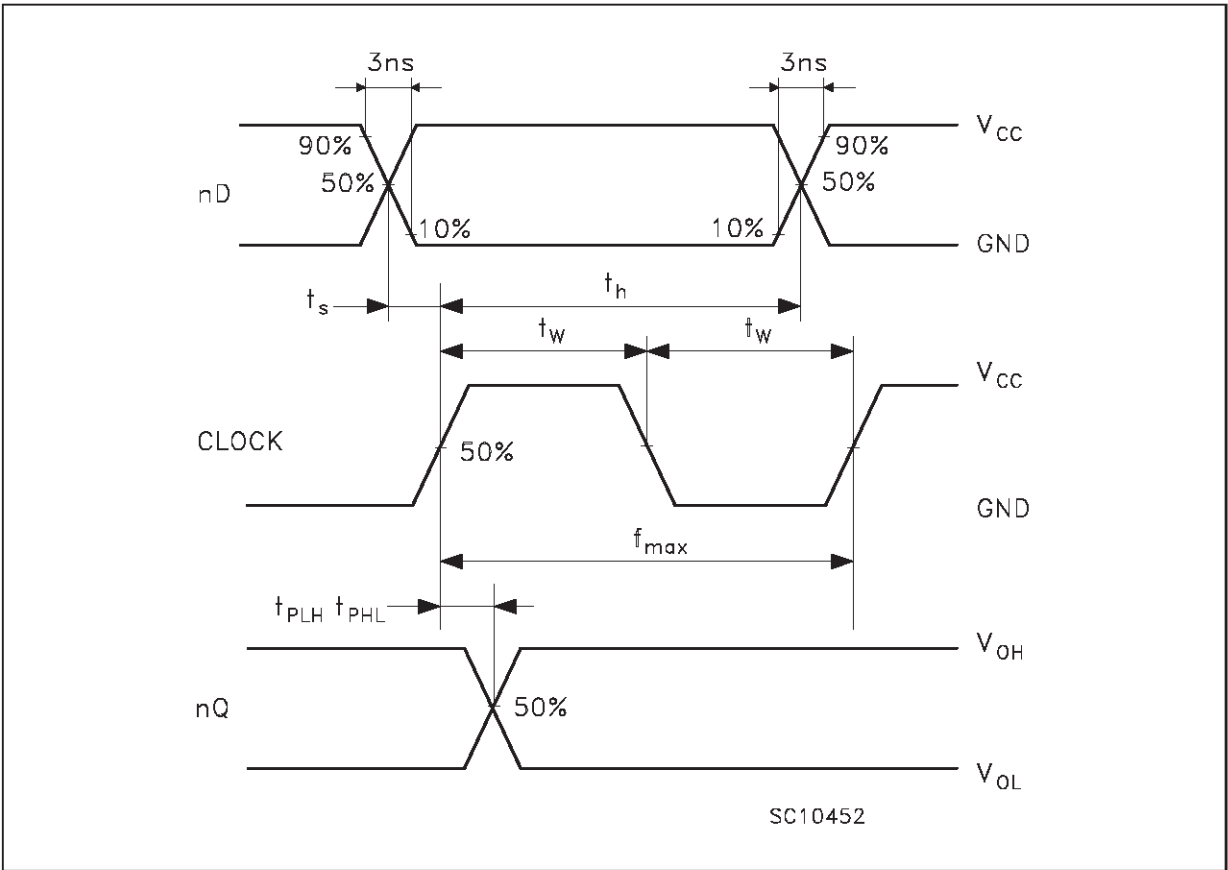
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC0}/n$ (per circuit)

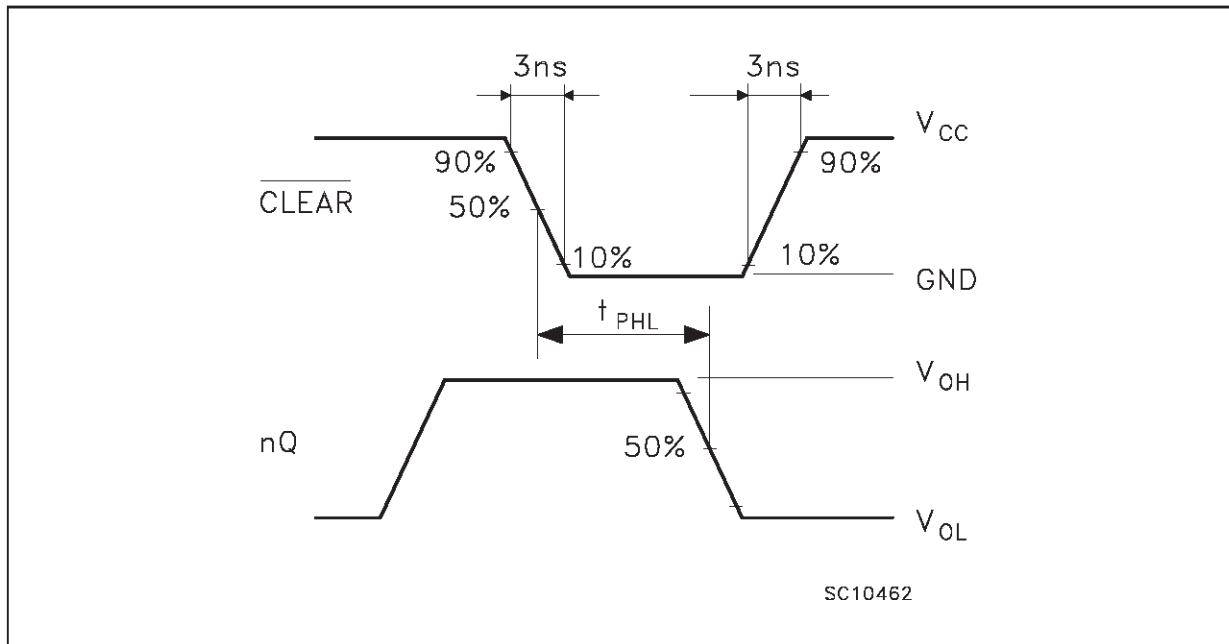
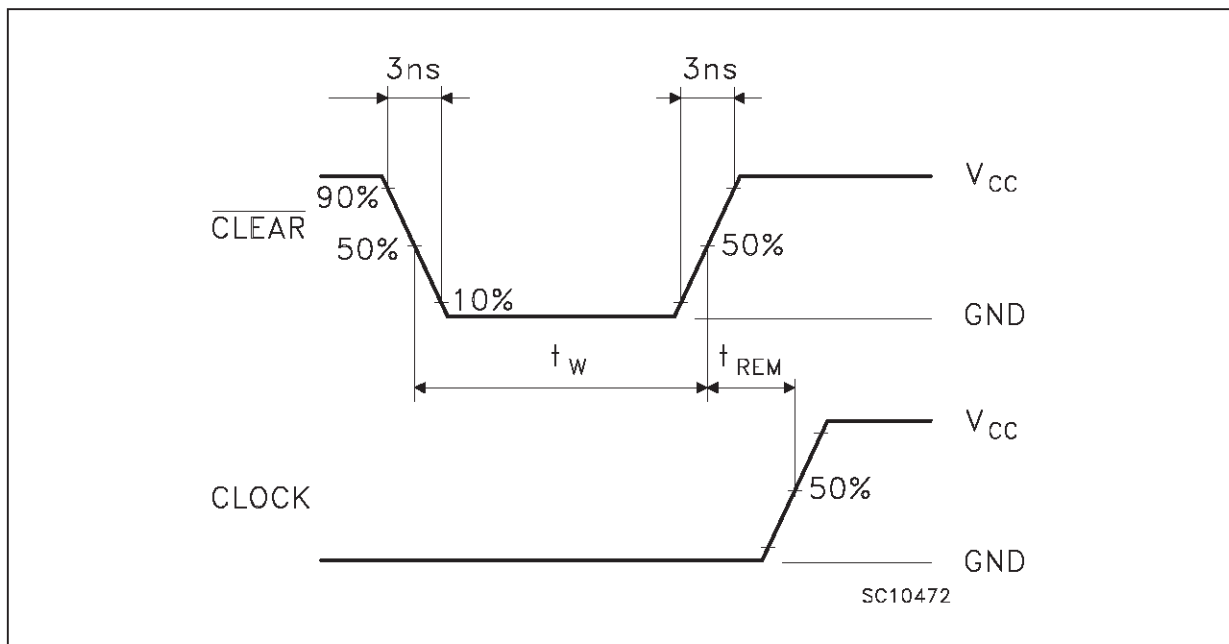
TEST CIRCUIT



C_L = 50 pF or equivalent (includes jig and probe capacitance)
 $R_L = R_1 = 500\Omega$ or equivalent
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

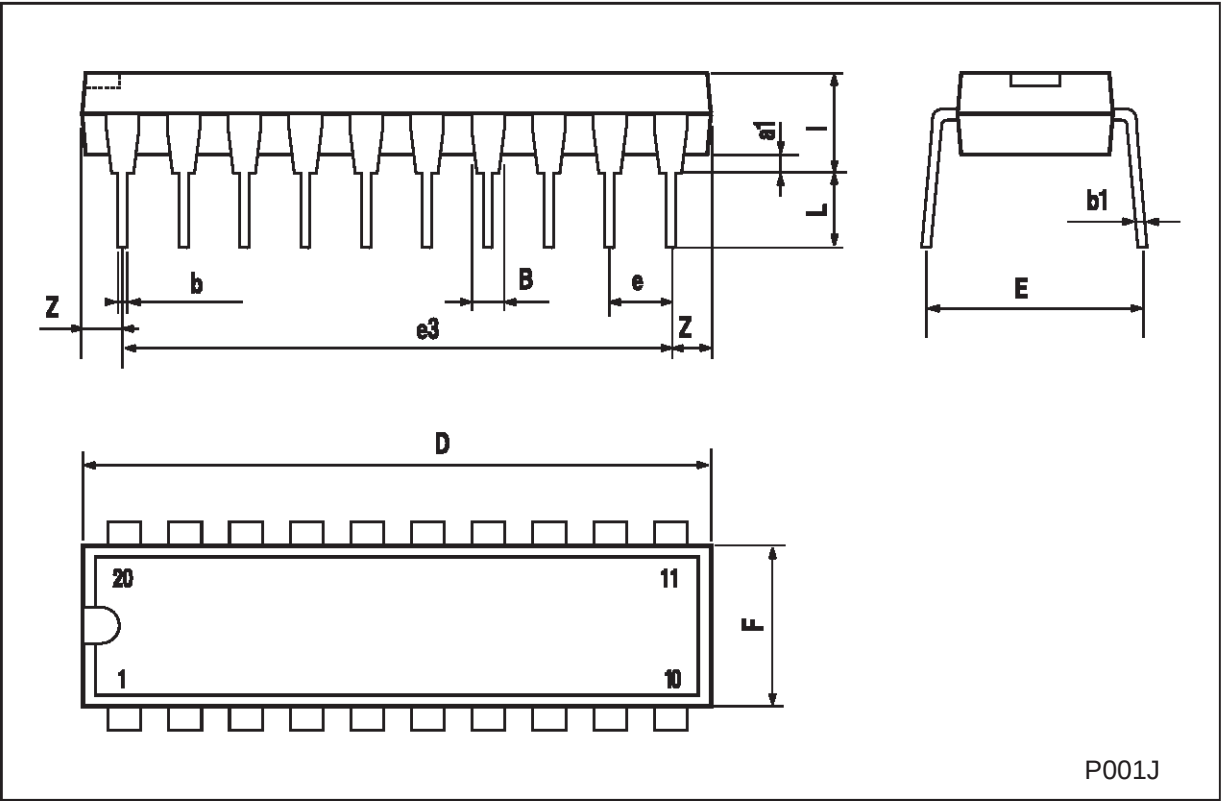
WAVEFORM 1: PROPAGATION DELAYS, SETUP AND HOLD TIMES ($f=1\text{MHz}$; 50% duty cycle)



WAVEFORM 2: PROPAGATION DELAYS ($f=1\text{MHz}$; 50% duty cycle)**WAVEFORM 3: RECOVERY TIME** ($f=1\text{MHz}$; 50% duty cycle)

Plastic DIP-20 (0.25) MECHANICAL DATA

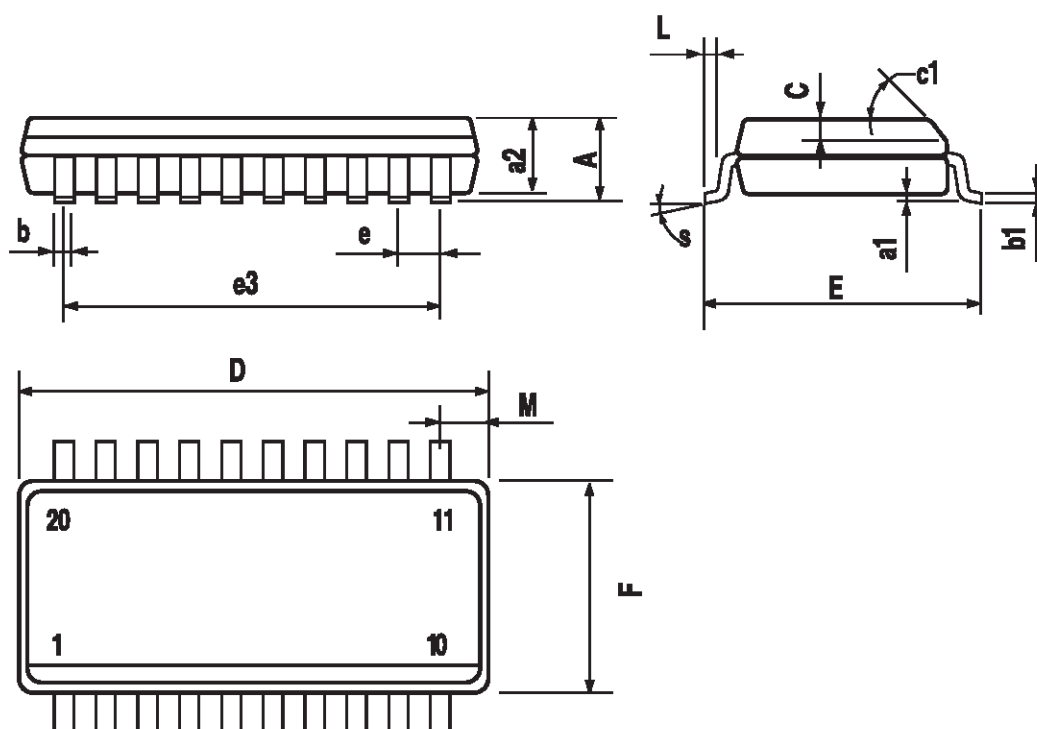
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.254			0.010		
B	1.39		1.65	0.055		0.065
b		0.45			0.018	
b1		0.25			0.010	
D			25.4			1.000
E		8.5			0.335	
e		2.54			0.100	
e3		22.86			0.900	
F			7.1			0.280
I			3.93			0.155
L		3.3			0.130	
Z			1.34			0.053



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SO-20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.10		0.20	0.004		0.007
a2			2.45			0.096
b	0.35		0.49	0.013		0.019
b1	0.23		0.32	0.009		0.012
C		0.50			0.020	
c1	45 (typ.)					
D	12.60		13.00	0.496		0.512
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		11.43			0.450	
F	7.40		7.60	0.291		0.299
L	0.50		1.27	0.19		0.050
M			0.75			0.029
S	8 (max.)					



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